# NSN 5961-01-145-2426

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# Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

# **Overall Width:**

1.050 inches

# Mounting Facility Quantity:

2

### Internal Configuration:

Junction contact

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

### To-3

Electrode Internally-electrically Connected To Case:

Collector

### Mounting Method:

Unthreaded hole

### Features Provided:

Hermetically sealed case

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

300.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 5.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

6.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

1 case and 2 pin

## **Specification Data:**

81349-mil-s-19500/510 government specification

## Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

